# NX3L4051

# Single low-ohmic 8-channel analog switch

Rev. 5 — 3 July 2012

**Product data sheet** 

## 1. General description

The NX3L4051 is a low-ohmic 8-channel analog switch, suitable for use as an analog or digital multiplexer/demultiplexer. The NX3L4051 has three digital select inputs (S1 to S3), eight independent inputs/outputs (Y0 to Y7) and a common input/output (Z). All eight switches share an enable input ( $\overline{E}$ ). A HIGH on  $\overline{E}$  causes all switches into the high impedance OFF-state, independent of Sn.

Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times. Low threshold digital inputs allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current  $I_{CC}$ . This makes it possible for the NX3L4051 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The NX3L4051 allows signals with amplitude up to  $V_{CC}$  to be transmitted from Z to Yn or from Yn to Z. Its low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ) ensures minimal attenuation and distortion of transmitted signals.

#### 2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - ♦ 1.7 Ω (typical) at V<sub>CC</sub> = 1.4 V
  - 1.0 Ω (typical) at V<sub>CC</sub> = 1.65 V
  - 0.6 Ω (typical) at V<sub>CC</sub> = 2.3 V
  - 0.5 Ω (typical) at V<sub>CC</sub> = 2.7 V
     0.5 Ω (typical) at V<sub>CC</sub> = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 7500 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM AEC-Q100-011 revision B exceeds 1000 V
  - ◆ IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at V<sub>CC</sub> = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V<sub>CC</sub>
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



#### Single low-ohmic 8-channel analog switch

# 3. Applications

- Cell phone
- PDA
- Portable media player
- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

# 4. Ordering information

#### Table 1. Ordering information

Type number	Package			
	Description	Version		
NX3L4051HR	–40 °C to +125 °C	HXQFN16	plastic thermal enhanced extremely thin quad flat package; no leads; 16 terminals; body $3\times3\times0.5$ mm	SOT1039-2
NX3L4051PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

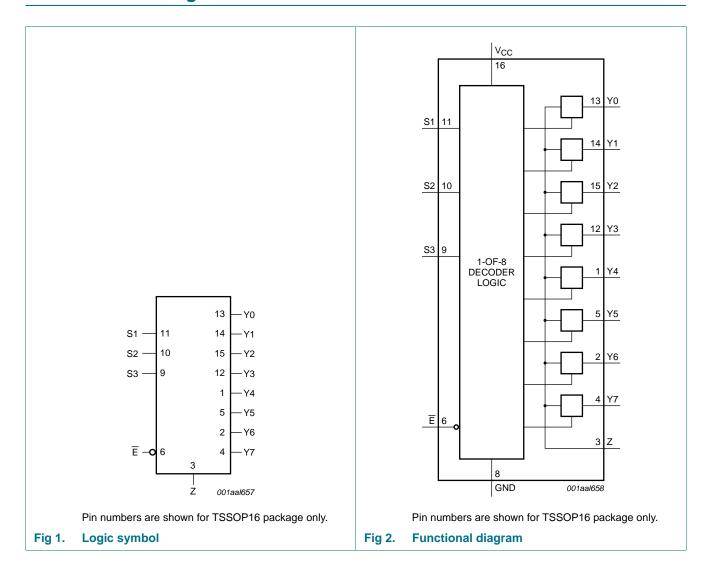
# 5. Marking

#### Table 2. Marking codes

Type number	Marking code
NX3L4051HR	M41
NX3L4051PW	X3L4051

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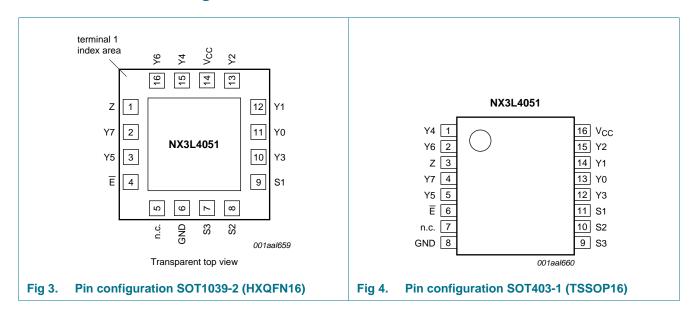
# 6. Functional diagram



#### Single low-ohmic 8-channel analog switch

# 7. Pinning information

#### 7.1 Pinning



### 7.2 Pin description

Table 3. Pin description

Symbol	Pin	Pin				
	SOT1039-2	SOT403-1				
Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7	11, 12, 13, 10, 15, 3, 16, 2	13, 14, 15, 12, 1, 5, 2, 4	independent input or output			
Z	1	3	independent output or input			
Ē	4	6	enable input (active LOW)			
n.c.	5	7	not connected			
GND	6	8	ground (0 V)			
S1, S2, S3	9, 8, 7	11, 10, 9	select input			
V <sub>CC</sub>	14	16	supply voltage			

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# 8. Functional description

Table 4. Function table[1]

Input	nput						
Ē	S3	S2	S1				
L	L	L	L	Y0 = Z			
L	L	L	Н	Y1 = Z			
L	L	Н	L	Y2 = Z			
L	L	Н	Н	Y3 = Z			
L	Н	L	L	Y4 = Z			
L	Н	L	Н	Y5 = Z			
L	Н	Н	L	Y6 = Z			
L	Н	Н	Н	Y7 = Z			
Н	X	X	X	switches off			

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care.

## 9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+4.6	V
VI	input voltage	Sn and E	<u>[1]</u> –0.5	+4.6	V
V <sub>SW</sub>	switch voltage		<u>[2]</u> −0.5	$V_{CC} + 0.5$	V
I <sub>IK</sub>	input clamping current	$V_1 < -0.5 \text{ V}$	-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±50	mA
I <sub>SW</sub>	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ source or sink current	-	±350	mA
		$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$			
		HXQFN16	<u>[3]</u> _	250	mW
		TSSOP16	<u>[4]</u> _	500	mW
-					

<sup>[1]</sup> The minimum input voltage rating may be exceeded if the input current rating is observed.

<sup>[2]</sup> The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

<sup>[3]</sup> For HXQFN16 package: above 135  $^{\circ}$ C the value of P<sub>tot</sub> derates linearly with 16.9 mW/K.

<sup>[4]</sup> For TSSOP16 package: above 60 °C the value of Ptot derates linearly with 5.5 mW/K above.

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# 10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		1.4	4.3	V
VI	input voltage	Sn and E	0	4.3	V
$V_{SW}$	switch voltage		<u>[1]</u> 0	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	Sn and $\overline{E}$ ; $V_{CC} = 1.4 \text{ V}$ to 4.3 V	-	200	ns/V

<sup>[1]</sup> To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

### 11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			$T_{amb} = -40$ °C to +125 °C			Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
$V_{IH}$	HIGH-level	V <sub>CC</sub> = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
	input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	1.3	-	-	1.3	-	-	V
		V <sub>CC</sub> = 3.6 V to 4.3 V	1.4	-	-	1.4	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
	V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V	
	V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V	
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V
I <sub>I</sub>	input leakage current	Sn and $\overline{E}$ ; $V_I = GND$ to 4.3 V; $V_{CC} = 1.4$ V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I <sub>S(OFF)</sub>	OFF-state	Yn ports; see Figure 5							
	leakage current	V <sub>CC</sub> = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nΑ
	current	V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
I <sub>S(ON)</sub>	ON-state leakage current	Z port; $V_{CC} = 1.4 \text{ V to } 3.6 \text{ V};$ see Figure 6							
		V <sub>CC</sub> = 1.4 V to 3.6 V	-	-	±20	-	±200	±2000	nΑ
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	±40	-	±200	±2000	nΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or $V_{CC}$							
		V <sub>CC</sub> = 3.6 V	-	-	100	-	500	5000	nΑ
		V <sub>CC</sub> = 4.3 V	-	-	150	-	800	6000	nA

NX3L4051

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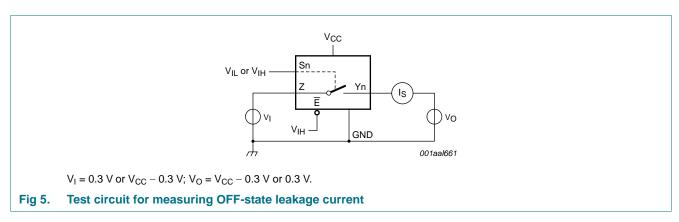
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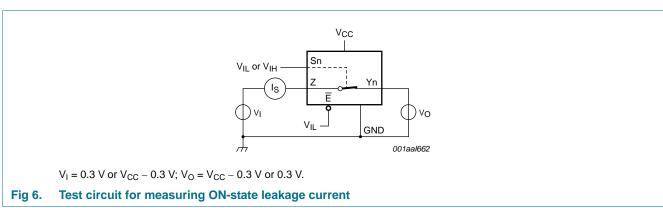
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**Table 7. Static characteristics** ...continued
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$			Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
$\Delta I_{CC}$ additional	$V_{SW} = GND \text{ or } V_{CC}$								
	supply current	$V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μΑ
	$V_1 = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μΑ	
		$V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	7.0	10.0	-	15	15	μА
		$V_{I} = 1.8 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	2.5	4.0	-	5	5	μА
		$V_{I} = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$	-	50	200	-	300	500	nA
Cı	input capacitance	Sn and E	-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance		-	350	-	-	-	-	pF

#### 11.1 Test circuits





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#### 11.2 ON resistance

Table 8. ON resistance[1]

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 14.

Symbol	Parameter	Conditions	Tan	<sub>b</sub> = -40 °	°C to +85 °C	$T_{amb} = -40$	$T_{amb} = -40$ °C to +125 °C		
			Mi	n Typ	[2] Max	Min	Max		
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}; \text{ see } \underline{\text{Figure 7}}$	'	'	'			•	
		$V_{CC} = 1.4 \text{ V}$	-	1.	7 3.7	-	4.1	Ω	
		V <sub>CC</sub> = 1.65 V	-	1.	0 1.6	-	1.7	Ω	
	$V_{CC} = 2.3 \text{ V}$	-	0.	6 0.8	-	0.9	Ω		
		$V_{CC} = 2.7 \text{ V}$	-	0.	5 0.75	-	0.9	Ω	
		$V_{CC} = 4.3 \text{ V}$	-	0.	5 0.75	-	0.9	Ω	
ΔR <sub>ON</sub> ON resistance mismatch		$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	[3]						
	between channels	$V_{CC} = 1.4 \text{ V}; V_{SW} = 0.4 \text{ V}$	-	0.1	8 0.30	-	0.30	Ω	
	Chamieis	$V_{CC} = 1.65 \text{ V}; V_{SW} = 0.5 \text{ V}$	-	0.1	8 0.20	-	0.30	Ω	
		$V_{CC} = 2.3 \text{ V}; V_{SW} = 0.7 \text{ V}$	-	0.0	0.10	-	0.13	Ω	
		$V_{CC} = 2.7 \text{ V}; V_{SW} = 0.8 \text{ V}$	-	0.0	0.10	-	0.13	Ω	
		$V_{CC} = 4.3 \text{ V}; V_{SW} = 0.8 \text{ V}$	-	0.0	0.10	-	0.13	Ω	
$R_{ON(flat)}$	ON resistance (flatness)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	[4]						
		$V_{CC} = 1.4 \text{ V}$	-	1.0	0 3.3	-	3.6	Ω	
		V <sub>CC</sub> = 1.65 V	-	0.	5 1.2	-	1.3	Ω	
		$V_{CC} = 2.3 \text{ V}$	-	0.1	5 0.3	-	0.35	Ω	
		$V_{CC} = 2.7 \text{ V}$	-	0.1	3 0.3	-	0.35	Ω	
		$V_{CC} = 4.3 \text{ V}$	-	0	2 0.4	-	0.45	Ω	

<sup>[1]</sup> For NX3L4051PW (TSSOP16 package), all ON resistance values are up to 0.05  $\Omega$  higher.

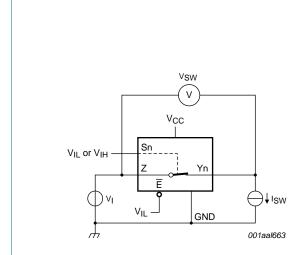
<sup>[2]</sup> Typical values are measured at  $T_{amb}$  = 25 °C.

<sup>[3]</sup> Measured at identical V<sub>CC</sub>, temperature and input voltage.

<sup>[4]</sup> Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

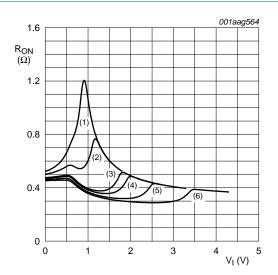
#### Single low-ohmic 8-channel analog switch

## 11.3 ON resistance test circuit and graphs



 $R_{ON} = V_{SW} / I_{SW}$ 

Fig 7. Test circuit for measuring ON resistance

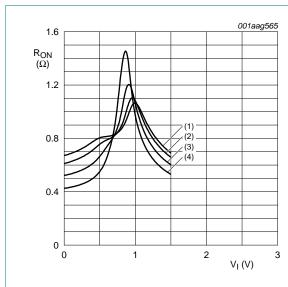


- (1)  $V_{CC} = 1.5 \text{ V}.$
- (2)  $V_{CC} = 1.8 \text{ V}.$
- (3)  $V_{CC} = 2.5 \text{ V}.$
- (4)  $V_{CC} = 2.7 \text{ V}.$
- (5)  $V_{CC} = 3.3 \text{ V}.$
- (6)  $V_{CC} = 4.3 \text{ V}.$

Measured at  $T_{amb}$  = 25 °C.

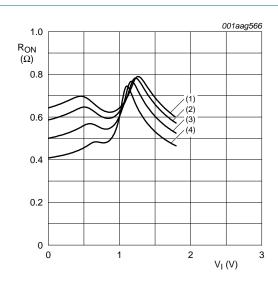
Fig 8. Typical ON resistance as a function of input voltage

#### Single low-ohmic 8-channel analog switch



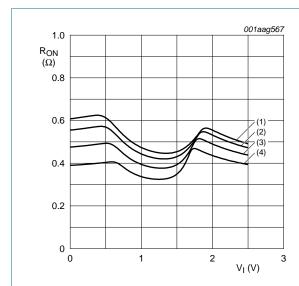
- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 9. ON resistance as a function of input voltage;  $V_{CC} = 1.5 \text{ V}$ 



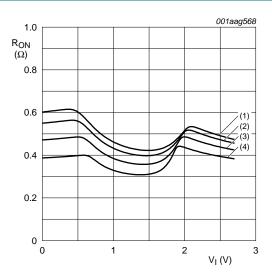
- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 10. ON resistance as a function of input voltage;  $V_{CC} = 1.8 \text{ V}$ 



- (1)  $T_{amb} = 125 \, ^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

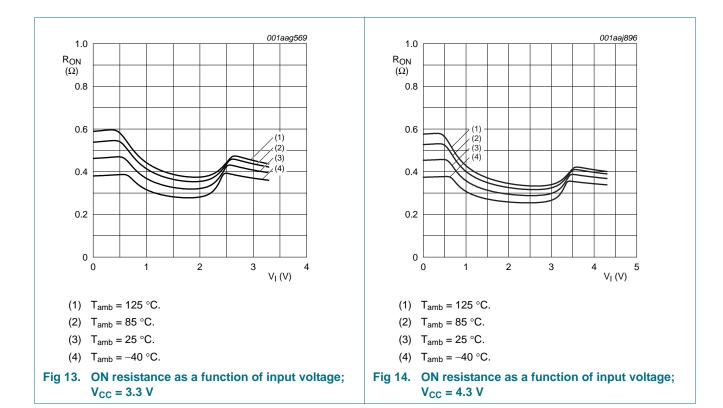
Fig 11. ON resistance as a function of input voltage;  $V_{CC} = 2.5 \text{ V}$ 



- (1)  $T_{amb} = 125 \,^{\circ}C$ .
- (2)  $T_{amb} = 85 \, ^{\circ}C$ .
- (3)  $T_{amb} = 25 \, ^{\circ}C$ .
- (4)  $T_{amb} = -40 \, ^{\circ}C$ .

Fig 12. ON resistance as a function of input voltage;  $V_{CC} = 2.7 \text{ V}$ 

## Single low-ohmic 8-channel analog switch



## 12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	nbol Parameter Conditions		Ta	<sub>mb</sub> = 25	°C	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$			Unit
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t <sub>en</sub>	enable time	E, Sn to Z or Yn; see Figure 15	•		•				
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	45	100	-	120	125	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	32	75	-	85	95	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	21	50	-	55	60	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	19	45	-	45	50	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	19	45	-	45	50	ns
t <sub>dis</sub>	disable time	E, Sn to Z or Yn; see Figure 15							
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	25	80	-	90	105	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	15	65	-	70	75	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	9	30	-	35	40	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	8	25	-	30	35	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	8	25	-	30	35	ns

## Single low-ohmic 8-channel analog switch

 Table 9.
 Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Parameter	Conditions		T <sub>amb</sub> = 25 °C		$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$			Unit	
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
$t_{b-m}$	break-before-make	see Figure 16	[2]							
	time	$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		-	19	-	9	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		-	17	-	7	-	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	12	-	4	-	-	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		-	10	-	3	-	-	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		-	9	-	2	-	-	ns

<sup>[1]</sup> Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

#### 12.1 Waveform and test circuits

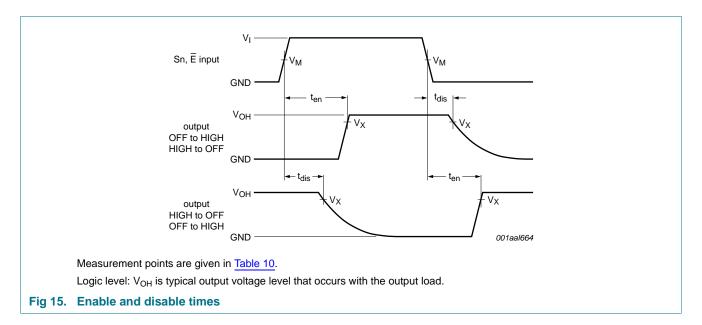
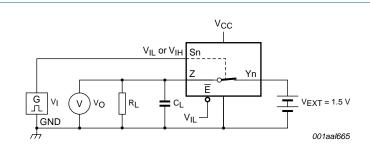


Table 10. Measurement points

Supply voltage	Input	Output
V <sub>CC</sub>	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

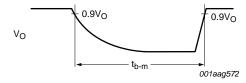
<sup>[2]</sup> Break-before-make guaranteed by design.

#### Single low-ohmic 8-channel analog switch



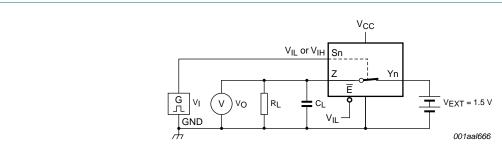
#### a. Test circuit





b. Input and output measurement points

Fig 16. Test circuit for measuring break-before-make timing



Test data is given in Table 11.

Definitions test circuit:

 $R_L$  = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $V_{EXT}$  = External voltage for measuring switching times.

 $V_I$  may be connected to Sn or  $\overline{E}$ .

Fig 17. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Input		Load	
V <sub>CC</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>
1.4 V to 4.3 V	V <sub>CC</sub>	≤ 2.5 ns	35 pF	50 Ω

#### Single low-ohmic 8-channel analog switch

## 12.2 Additional dynamic characteristics

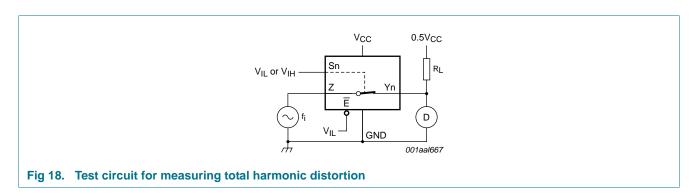
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = \text{GND}$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5$  ns;  $T_{amb} = 25$  °C.

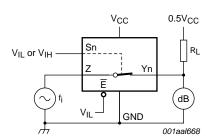
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic	$f_i$ = 20 Hz to 20 kHz; $R_L$ = 32 $\Omega$ ; see Figure 18	<u>[1]</u>			
	distortion	$V_{CC} = 1.4 \text{ V}; V_I = 1 \text{ V (p-p)}$	-	0.15	-	%
		$V_{CC} = 1.65 \text{ V}; V_I = 1.2 \text{ V (p-p)}$	-	0.10	-	%
		$V_{CC} = 2.3 \text{ V}; V_I = 1.5 \text{ V (p-p)}$	-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; V_{I} = 2 \text{ V (p-p)}$	-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; V_{I} = 2 \text{ V (p-p)}$	-	0.02	-	%
f <sub>(-3dB)</sub>	-3 dB frequency	$R_L = 50 \Omega$ ; see Figure 19	[1]			
	response	V <sub>CC</sub> = 1.4 V to 4.3 V	-	15	-	MHz
$\alpha_{\text{iso}}$ isolation	isolation (OFF-state)	$f_i$ = 100 kHz; $R_L$ = 50 $\Omega$ ; see Figure 20	[1]			
		V <sub>CC</sub> = 1.4 V to 4.3 V	-	-90	-	dB
$V_{ct}$	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see Figure 21				
		V <sub>CC</sub> = 1.4 V to 3.6 V	-	0.2	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	0.3	-	V
Xtalk	crosstalk	between switches; $f_i = 100 \text{ kHz}$ ; $R_L = 50 \Omega$ ; see Figure 22	[1]			
		V <sub>CC</sub> = 1.4 V to 4.3 V	-	-90	-	dB
Q <sub>inj</sub>	charge injection	$f_i$ = 1 MHz; $C_L$ = 0.1 nF; $R_L$ = 1 M $\Omega$ ; $V_{gen}$ = 0 V; $R_{gen}$ = 0 $\Omega$ ; see <u>Figure 23</u>				
		V <sub>CC</sub> = 1.5 V	-	3	-	рС
		V <sub>CC</sub> = 1.8 V	-	4	-	рС
		V <sub>CC</sub> = 2.5 V	-	6	-	рС
		$V_{CC} = 3.3 \text{ V}$	-	9	-	рС
		V <sub>CC</sub> = 4.3 V	-	15	-	рС

<sup>[1]</sup>  $f_i$  is biased at  $0.5V_{CC}$ .

#### 12.3 Test circuits

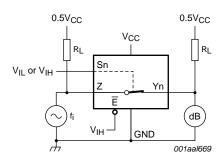


#### Single low-ohmic 8-channel analog switch



Adjust  $f_i$  voltage to obtain 0 dBm level at output. Increase  $f_i$  frequency until dB meter reads -3 dB.

Fig 19. Test circuit for measuring the frequency response when channel is in ON-state



Adjust fi voltage to obtain 0 dBm level at input.

Fig 20. Test circuit for measuring isolation (OFF-state)

#### Single low-ohmic 8-channel analog switch

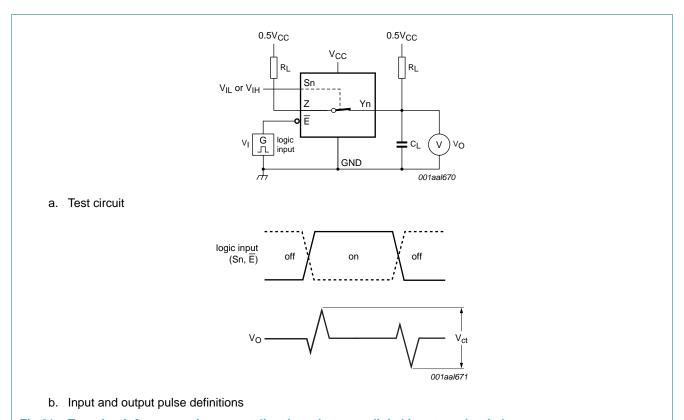


Fig 21. Test circuit for measuring crosstalk voltage between digital inputs and switch

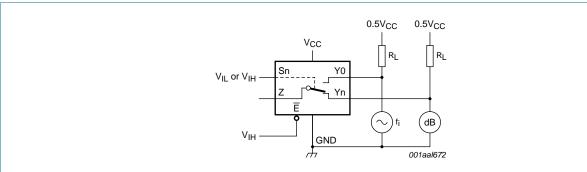
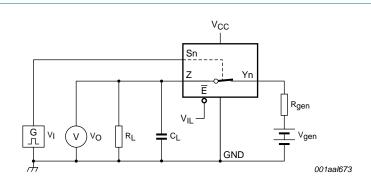
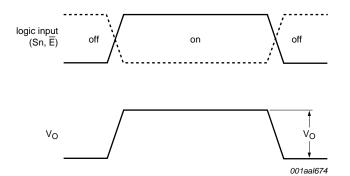


Fig 22. Test circuit for measuring crosstalk between switches

### Single low-ohmic 8-channel analog switch



a. Test circuit



b. Input and output pulse definitions

Definition:  $Q_{inj} = \Delta V_O \times C_L$ .

 $\Delta V_{O}$  = output voltage variation.

R<sub>gen</sub> = generator resistance.

V<sub>gen</sub> = generator voltage.

 $V_I$  may be connected to Sn or  $\overline{E}$ .

Fig 23. Test circuit for measuring charge injection

#### Single low-ohmic 8-channel analog switch

# 13. Package outline

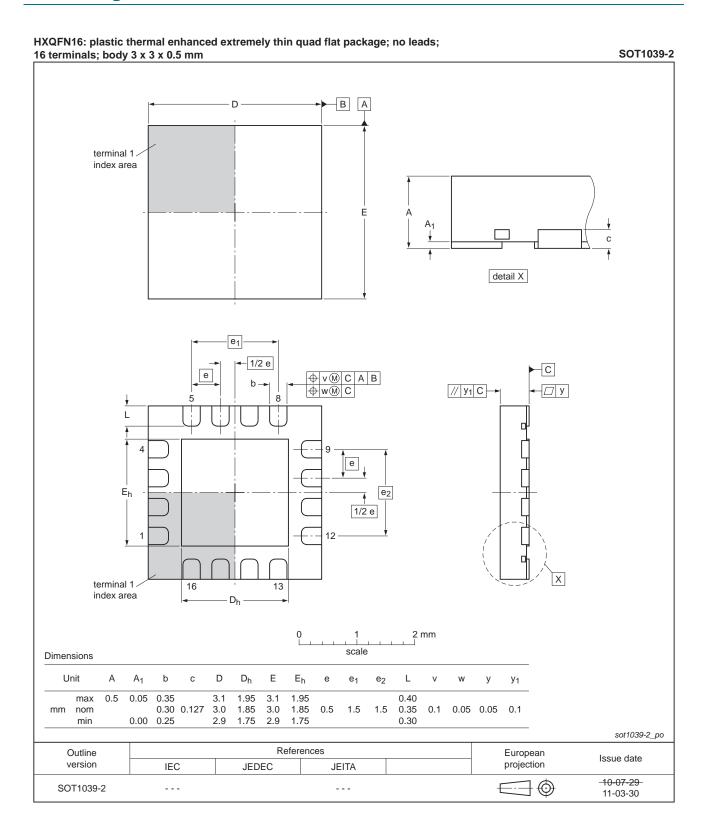


Fig 24. Package outline SOT1039-2 (HXQFN16)

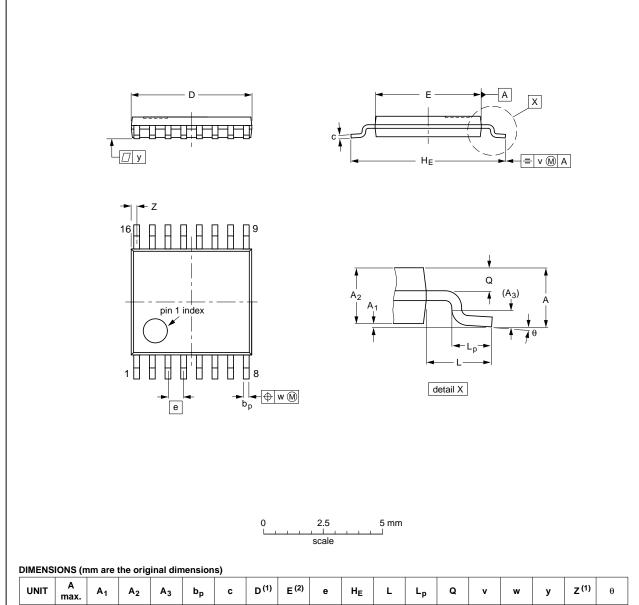
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#### Single low-ohmic 8-channel analog switch

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18	
501403-1		IVIO-153				<u> </u>	

Fig 25. Package outline SOT403-1 (TSSOP16)

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### Single low-ohmic 8-channel analog switch

# 14. Abbreviations

#### Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
PDA	Personal Digital Assistant

# 15. Revision history

#### Table 14. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L4051 v.5	20120703	Product data sheet	-	NX3L4051 v.4
Modifications:	<ul> <li>For type null</li> </ul>	mber NX3L4051HR the sot	code has changed to SC	DT1039-2.
NX3L4051 v.4	20111107	Product data sheet	-	NX3L4051 v.3
Modifications:	<ul> <li>Legal pages</li> </ul>	s updated.		
NX3L4051 v.3	20101222	Product data sheet	-	NX3L4051 v.2
NX3L4051 v.2	20100812	Product data sheet	-	NX3L4051 v.1
NX3L4051 v.1	20100415	Product data sheet	-	-

#### Single low-ohmic 8-channel analog switch

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#### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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